Appl. No. 10/572,924; Docket No.: US03 0345 US2

Amdt. Dated: December 12, 2008

Response to Office Action dated September 26, 2008

REMARKS/ARGUMENTS

In response to the Examiner's comments, Applicant has amended the Specification to conform to the replacement drawing sheet of FIG. 1. The gate oxide is now shown at 117. The nitride layer has been indicated to be disposed under the field plate 109. Missing legend 104, denoting field oxide, was added to drawing These changes are supported in the application and contain no new matter.

Applicant believes that the case is ready for issue.

Please charge any fees other than the issue fee and credit any overpayments to Deposit Account <u>50-4019</u>.

Respectfully submitted,

Date: December 12, 2008 By: /Peter Zawilski/

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